

LEVEL SHIFTER

This document presents the simulation and output of the Level shifter based on a regulated cross-coupled pull-up network.

- A level shifter is a circuit that converts signal voltage levels between different domains, allowing safe communication between components operating at different voltage standards. It ensures compatibility in mixed-voltage systems commonly found in modern integrated circuits.
- The basic architecture of a CMOS level shifter usually includes a pair of cross-coupled inverters, which form a bistable circuit, and a pair of NMOS and PMOS transistors that manage the level conversion.

Working Principle

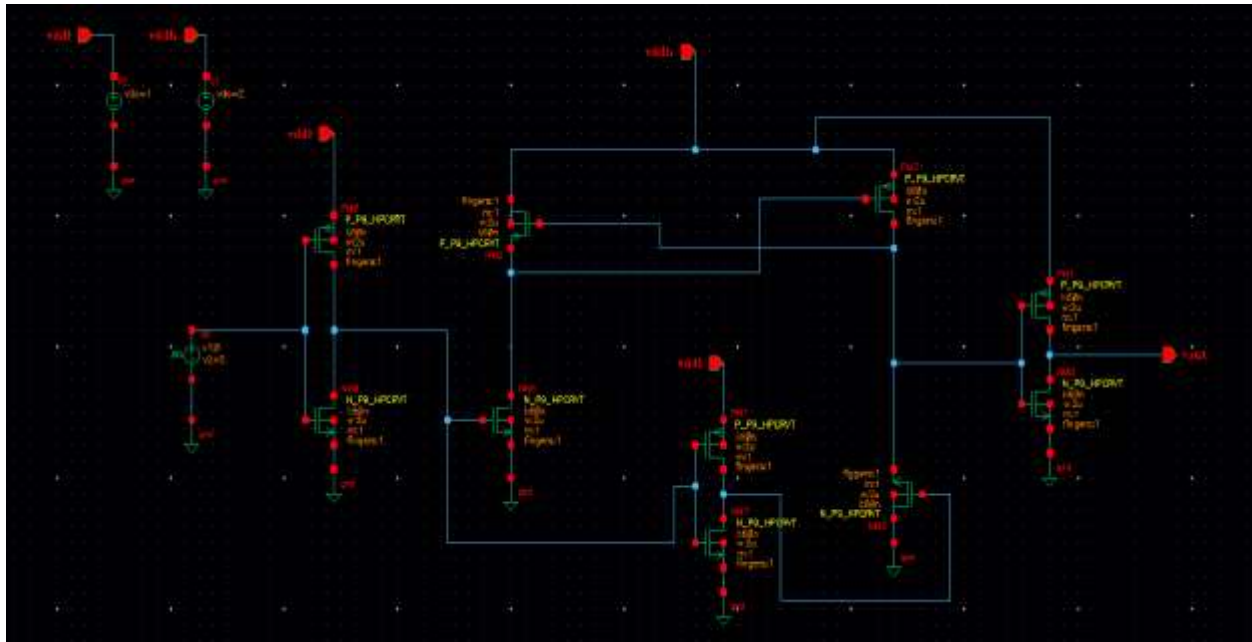
High-to-Low Conversion

- Initial State: If $V_{DDH} = 0$ and $V_{DDL} = 0$, the input voltage (e.g., 1.8mV) will decay towards microvolts due to leakage currents in the circuit.
- Voltage Translation: When $V_{DDH} = 0$ and V_{DDL} is increased incrementally, the input voltage is translated from volts to millivolts proportionally.
- This ensures proper high-to-low transition at the output.

Low-to-High Conversion

- Operation: When $V_{DDH} > V_{DDL}$ and the input voltage is less than V_{DDH} , the circuit converts the output to the high voltage domain.
- For example, with an input of 2V and an output requirement of 5V, set $V_{DDH} = 5V$ and ensure $V_{DDL} < V_{DDH}$.
- Output Dependence: The output voltage always depends on the values of V_{DDH} and V_{DDL} , ensuring flexibility for various use cases.

Schematic of Level shifter



Simulation Results

	VDDH	VDDL	INPUT	OUTPUT
HIGH TO LOW	0V	0V	In millivolts	In microvolts
	0V	1V	In volts	In millivolts
	2V	1V	5V	2V
LOW TO HIGH	5V	1V	2V	5V
	3V	2V	1.8V	3V

Transient Analysis

1. Perform a transient simulation to analyze the level shifter's performance over time.
2. Observe the input and output waveforms to ensure proper level shifting

Results and Simulations

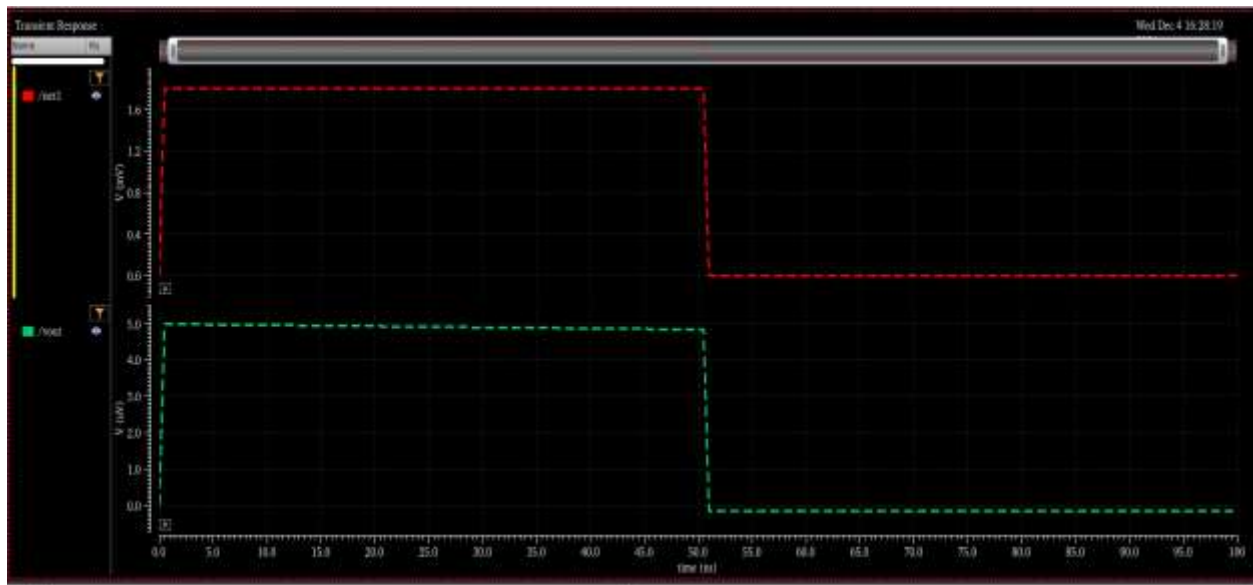


Fig 7.1.1 Transient response of high to low level shift (millivolts to microvolts)

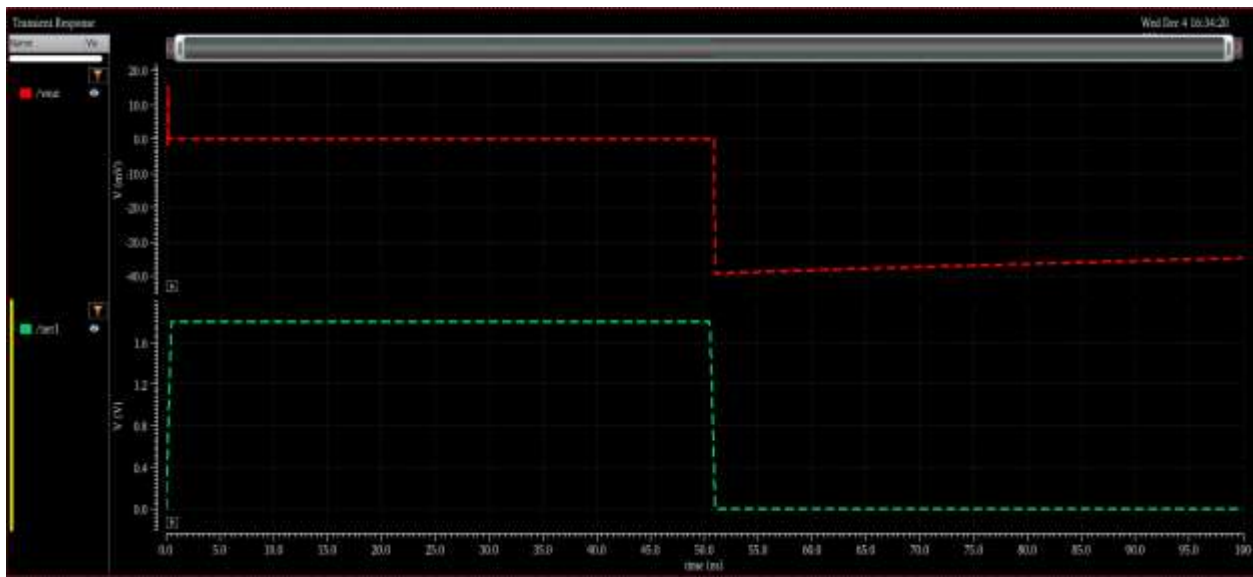


Fig 7.1.2 Transient response of high to low level shift (volts to millivolts)

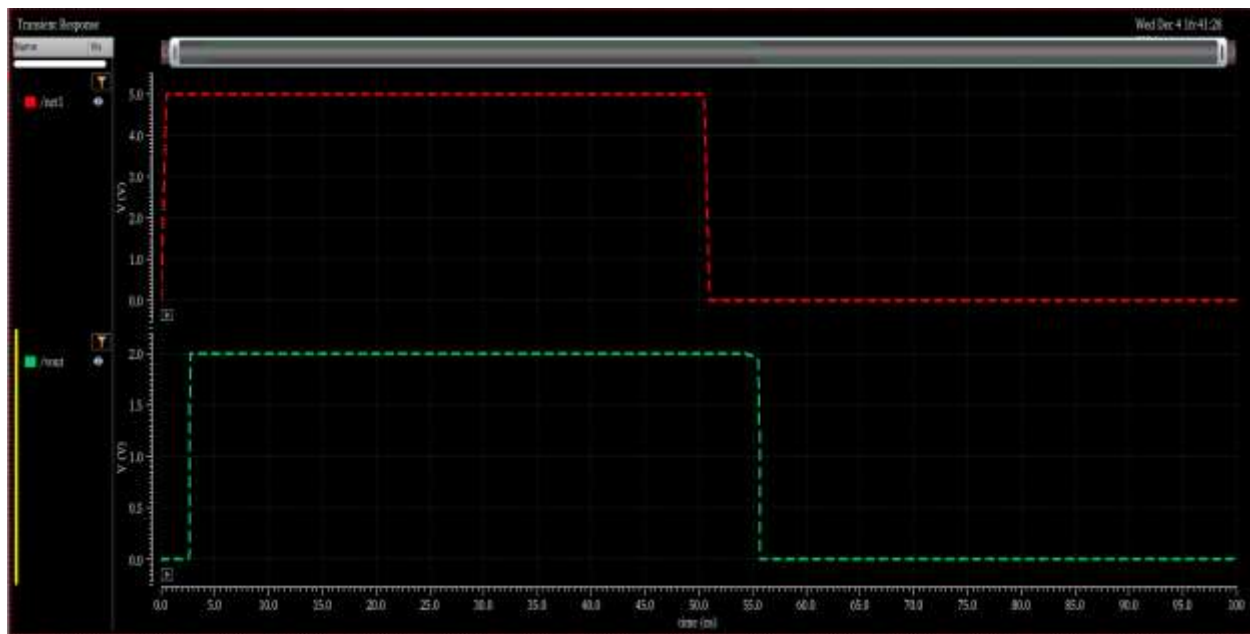


Fig 7.1.3 Transient response of high to low level shift (5volts to 2 volts)

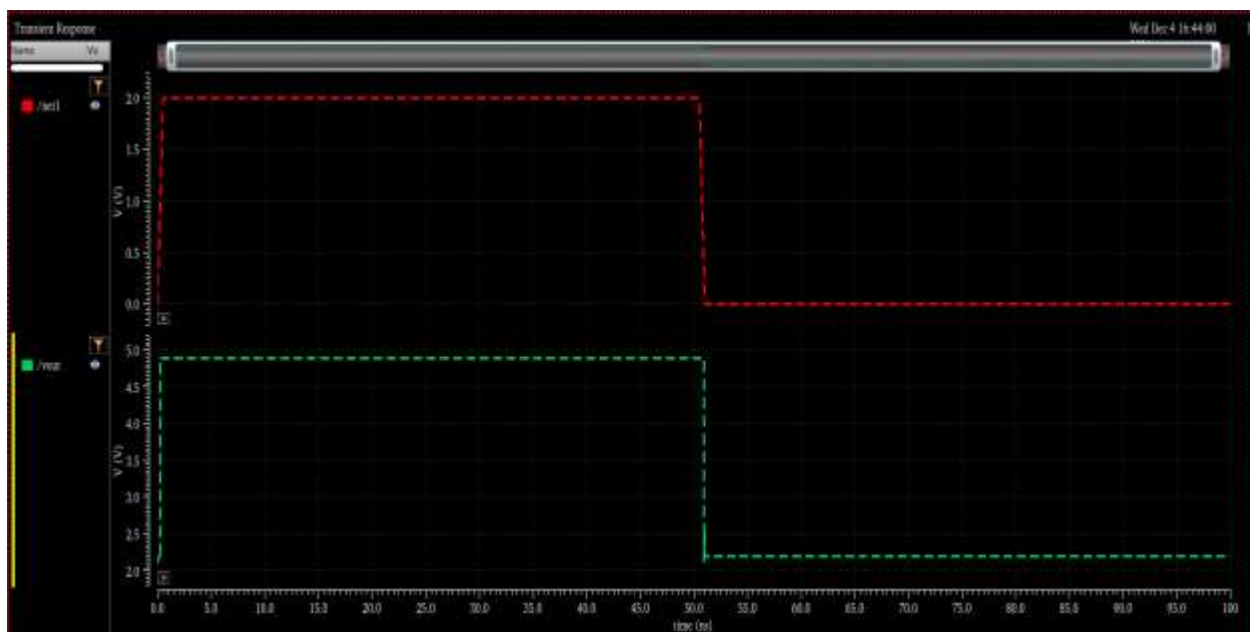


Fig 7.1.4 Transient response of low to high level shift (2volts to 5volts)

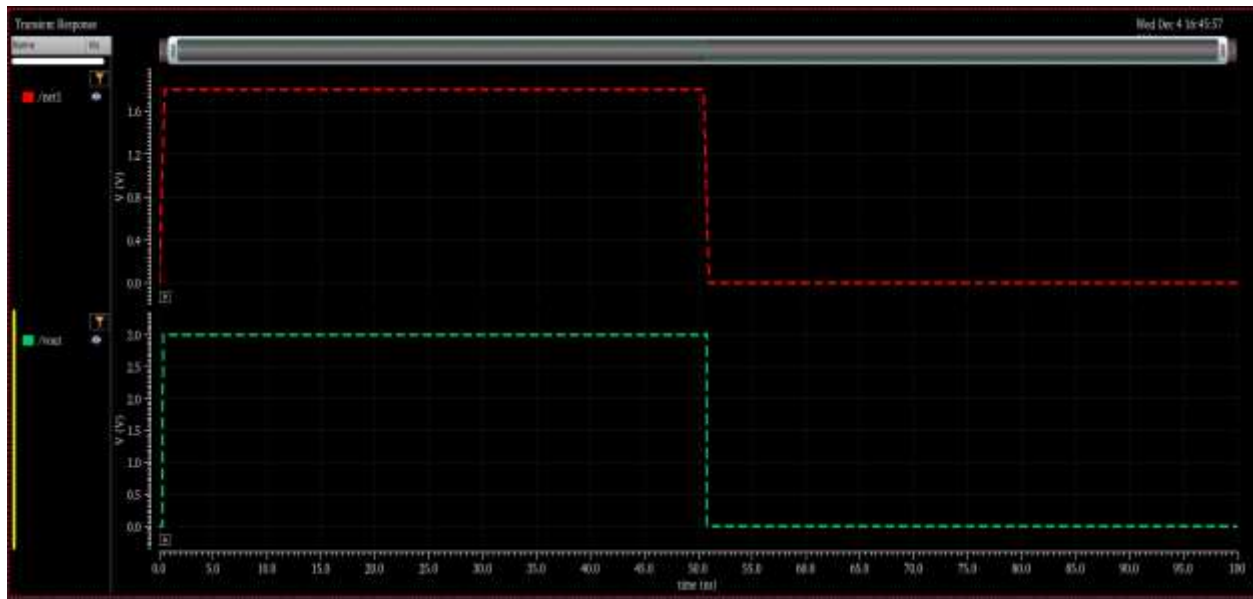


Fig 7.1.5 Transient response of low to high level shift (1.8volts to 3volts)

Conclusion

A voltage level shifter using a cascade voltage switch with a regulated cross-coupled pull-up network was simulated in Cadence with 28 nm CMOS technology. It effectively handled voltage shifts from high to low and low to high (e.g., 5V to 2V, 1.8V to 3V), with low static power consumption due to the cross-coupled design reducing direct paths from supply to ground.